# PH1214-100EL



## Radar Pulsed Power Transistor 100W, 1.2-1.4 GHz, 2ms Pulse, 20% Duty

M/A-COM Products Released, 30 May 07

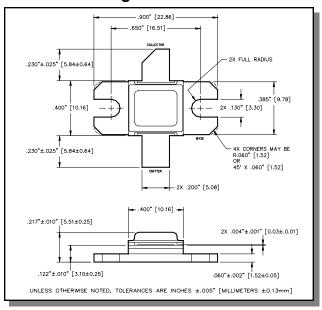
#### **Features**

- NPN silicon microwave power transistors
- Common base configuration
- Broadband Class C operation
- High efficiency inter-digitized geometry
- · Diffused emitter ballasting resistors
- Gold metallization system
- · Internal input and output impedance matching
- Hermetic metal/ceramic package
- RoHS compliant

### Absolute Maximum Ratings at 25°C

Parameter	Symbol	Rating	Units
Collector-Emitter Voltage	$V_{CES}$	75	V
Emitter-Base Voltage	$V_{EBO}$	3.0	V
Collector Current (Peak)	Ι <sub>C</sub>	14.1	Α
Power Dissipation @ +25°C	P <sub>TOT</sub>	250	W
Storage Temperature	T <sub>STG</sub>	-65 to +200	°C
Junction Temperature	$T_J$	200	°C

#### **Outline Drawing**



## Electrical Specifications: T<sub>C</sub> = 25 ± 5°C (Room Ambient)

Parameter	Test Conditions	Frequency	Symbol	Min	Max	Units
Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 50mA		BV <sub>CES</sub>	70	-	V
Collector-Emitter Leakage Current	V <sub>CE</sub> = 28V		I <sub>CES</sub>	-	10	mA
Thermal Resistance	Vcc = 28V, Pin = 25W	F = 1.2, 1.3, 1.4 GHz	R <sub>TH(JC)</sub>	-	0.7	°C/W
Output Power	Vcc = 28V, Pin = 25W	F = 1.2, 1.3, 1.4 GHz	P <sub>OUT</sub>	100	=	W
Power Gain	Vcc = 28V, Pin = 25W	F = 1.2, 1.3, 1.4 GHz	G <sub>P</sub>	6.0	=	dB
Collector Efficiency	Vcc = 28V, Pin = 25W	F = 1.2, 1.3, 1.4 GHz	ης	52	-	%
Input Return Loss	Vcc = 28V, Pin = 25W	F = 1.2, 1.3, 1.4 GHz	RL	-	-8	dB
Load Mismatch Tolerance	Vcc = 28V, Pin = 25W	F = 1.2, 1.3, 1.4 GHz	VSWR-T	-	3:1	-
Load Mismatch Stability	Vcc = 28V, Pin = 25W	F = 1.2, 1.3, 1.4 GHz	VSWR-S	-	1.5:1	-

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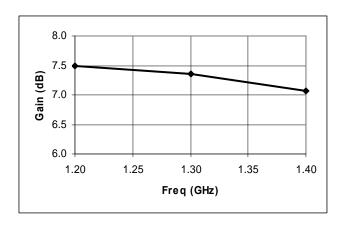


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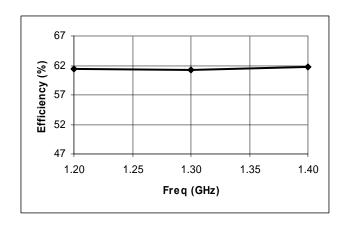
### **Typical RF Performance**

Freq. (GHz)	Pin (W)	Pout (W)	Gain (dB)	Ic (A)	Eff (%)	RL (dB)	VSWR-S (1.5:1)	VSWR-T (3:1)
1.2	25	140	7.48	16.3	61.4	-14.9	S	Р
1.3	25	136	7.35	15.8	61.3	-13.5	S	Р
1.4	25	127	7.07	14.7	61.8	-13.9	S	Р

#### Gain vs. Frequency

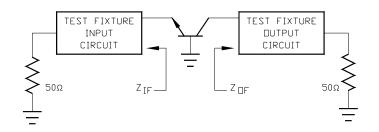


#### Collector Efficiency vs. Frequency



### **RF Test Fixture Impedance**

F (GHz)	Z <sub>IF</sub> (Ω)	Z <sub>OF</sub> (Ω)
1.2	2.6 - j3.8	3.0 - j2.7
1.3	3.0 - j3.4	2.4 - j2.6
1.4	3.4 - j3.1	1.9 - j2.5



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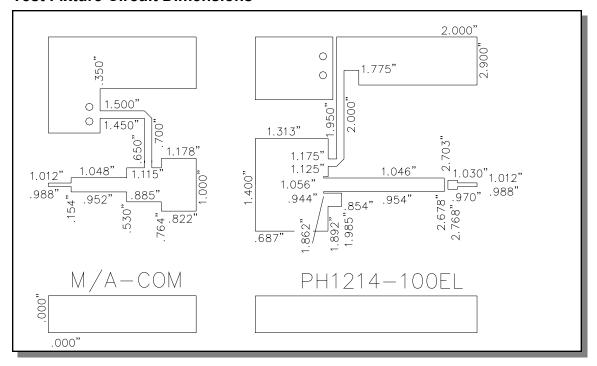
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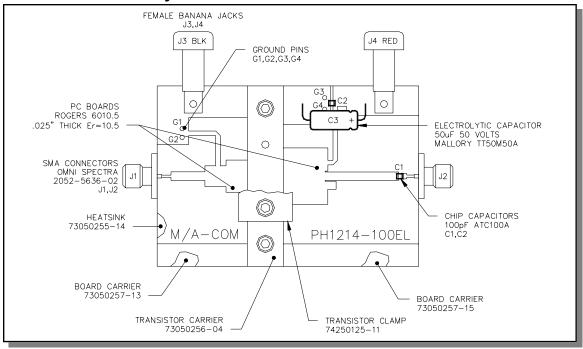


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#### **Test Fixture Circuit Dimensions**



### **Test Fixture Assembly**



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